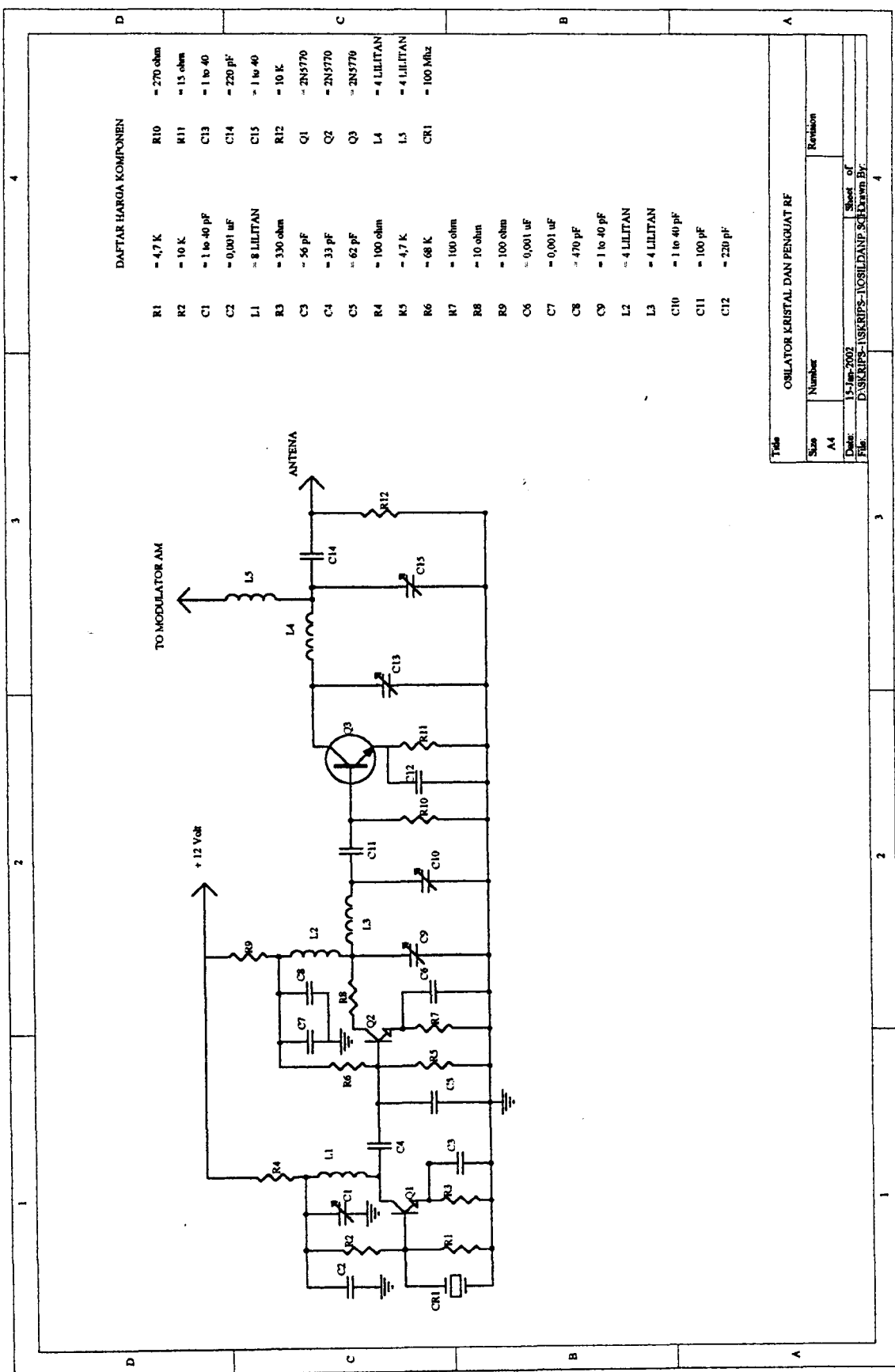


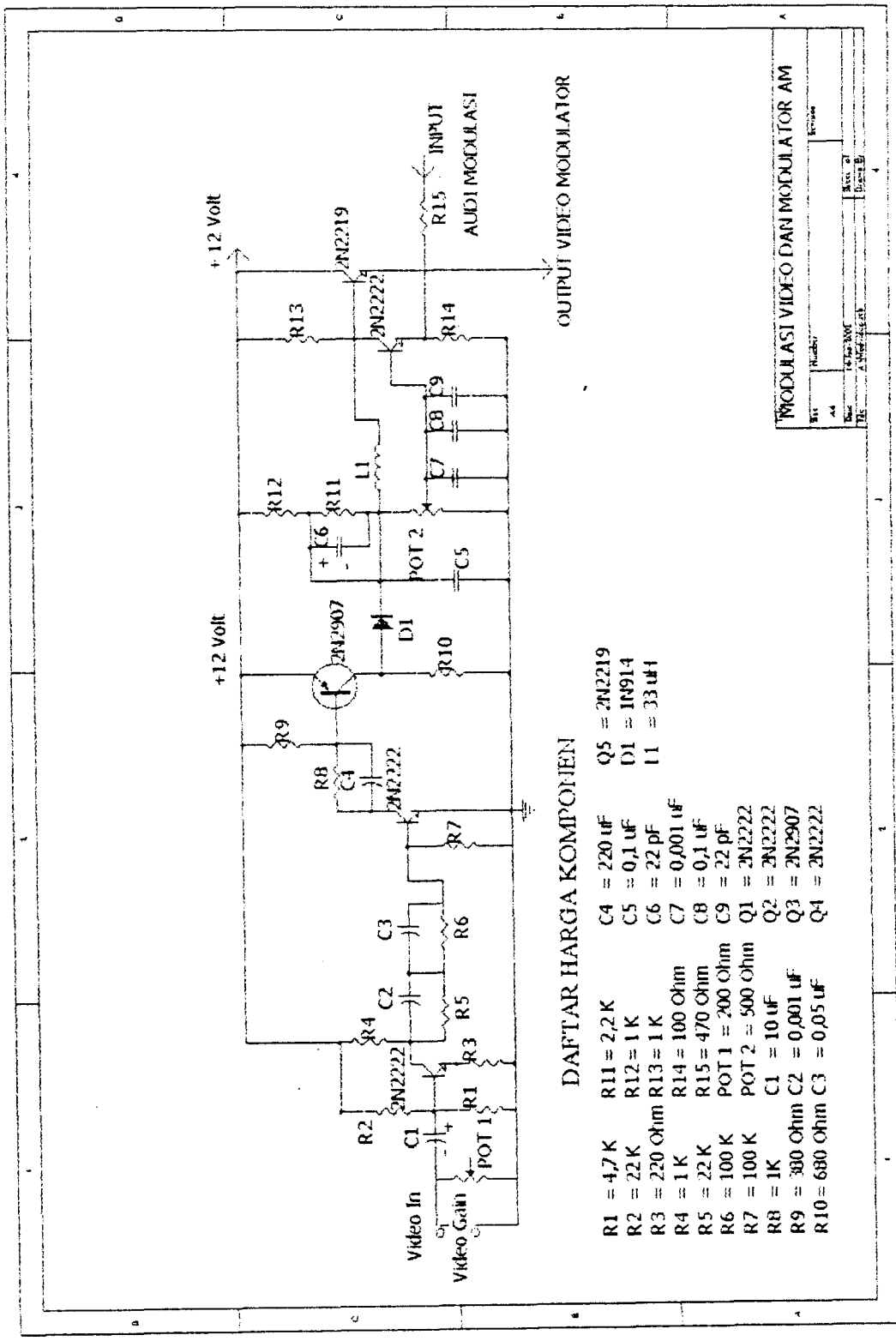
## LAMPIRAN A



DAFTAR HARGA KOMPONEN

R1	- 4,7 K	R10	- 270 ohm
R2	- 10 K	R11	- 15 ohm
C1	- 1 to 40 pF	C13	- 1 to 40
C2	- 0,001 uF	C14	- 220 pF
L1	- 8 LILITAN	C15	- 1 to 40
R3	- 330 ohm	R12	- 10 K
C3	- 56 pF	Q1	- 2N3770
C4	- 33 pF	Q2	- 2N3770
C5	- 62 pF	Q3	- 2N3770
R4	- 100 ohm	L4	- 4 LILITAN
R5	- 4,7 K	L5	- 4 LILITAN
R6	- 68 K	CR1	- 100 Mhz
R7	- 100 ohm		
R8	- 10 ohm		
R9	- 100 ohm		
C6	- 0,001 uF		
C7	- 0,001 uF		
C8	- 470 pF		
C9	- 1 to 40 pF		
L2	- 4 LILITAN		
L3	- 4 LILITAN		
C10	- 1 to 40 pF		
C11	- 100 pF		
C12	- 220 pF		

Title		OSILATOR KRISTAL DAN PENGUAT RF	
Size	Number	Revision	
A4			
Date:	15-Jan-2002	Sheet of	
File:	D:\SKRIPSI-1\SKRIPSI-1\OSILATOR RF	Drawn By:	



**DAFTAR HARGA KOMPONEN**

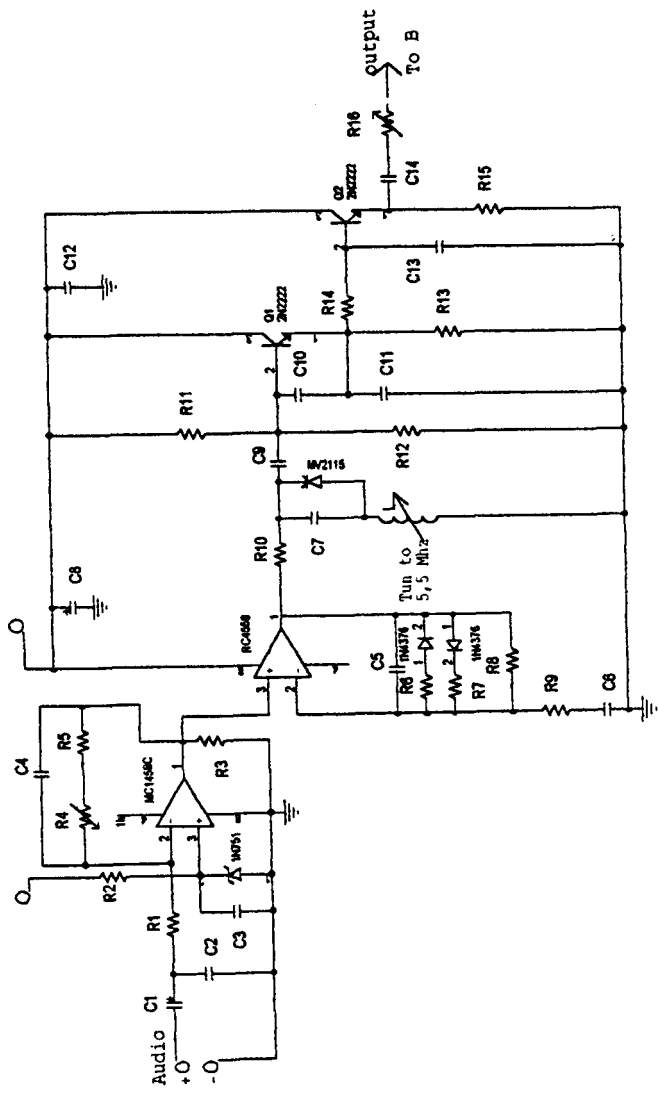
R1 = 4,7 K	R11 = 2,2 K	C4 = 220 uF	Q5 = 2N2219
R2 = 22 K	R12 = 1 K	C5 = 0,1 uF	D1 = 1N914
R3 = 220 Ohm	R13 = 1 K	C6 = 22 pF	I1 = 33 uH
R4 = 1 K	R14 = 100 Ohm	C7 = 0,001 uF	
R5 = 22 K	R15 = 470 Ohm	C8 = 0,1 uF	
R6 = 100 K	POT1 = 200 Ohm	C9 = 22 pF	
R7 = 100 K	POT2 = 500 Ohm	Q1 = 2N2222	
R8 = 1 K	C1 = 10 uF	Q2 = 2N2222	
R9 = 380 Ohm	C2 = 0,001 uF	Q3 = 2N2907	
R10 = 680 Ohm	C3 = 0,05 uF	Q4 = 2N2222	

MODULASI VIDEO DAN MODULATOR AM

REVISI	NO. 4	REVISI	NO. 3
NO. 4	REVISI	NO. 2	REVISI
NO. 3	REVISI	NO. 1	REVISI

# RANGKAIAN MODULASI AUDIO

12 Volt



## DAFTAR HARGA KOMPONEN

- |               |               |             |             |                |                |
|---------------|---------------|-------------|-------------|----------------|----------------|
| C1 = 1 uF     | R4 = 100 K    | D2 = 1N914  | R10 = 10 K  | R11 = 22 K     | C12 = 0,01 uF  |
| C2 = 0,001 uF | R5 = 2200 Ohm | R7 = 1 K    | C7 = 47 pF  | R12 = 10 K     | C13 = 33 pF    |
| C3 = 0,01 Uf  | C4 = 10 uF    | D3 = 1N914  | L = 18 uH   | C10 = 470 pF   | R15 = 470 Ohm  |
| R1 = 100 Ohm  | R3 = 10 K     | R8 = 100 K  | D4 = MV2115 | C11 = 470pF    | C14 = 470 pF   |
| R2 = 100 Ohm  | C5 = 470 pF   | R9 = 1 K    | C8 = 100 uF | R14 = 1 K      | R16 = 2500 Ohm |
| D1 = 1N751    | R6 = 1 K      | C6 = 1 uF   | C9 = 470 pF | R13 = 2200 Ohm | IC 1 = MC1458  |
| IC 2 = RC4558 | Q1 = 2N2222   | Q2 = 2N2222 |             |                |                |

LAMPIRAN B

**2N2218,A/2N2219,A  
2N2221,A/2N2222,A  
2N5581/82**

JAN, JTX, JTXV AVAILABLE

2N2218,A  
2N2219,A  
CASE 79-02  
TO-39 (TO-205AD) STYLE 1

2N2221,A  
2N2222,A  
CASE 22-03  
TO-18 (TO-206AA) STYLE 1

2N5581  
2N5582  
CASE 26-03  
TO-46 (TO-206AB) STYLE 1



**GENERAL PURPOSE TRANSISTOR**  
NPN SILICON

**MAXIMUM RATINGS**

Rating	Symbol	2N2218 2N2219 2N2221 2N2222	2N2218A 2N2219A 2N2221A 2N2222A	2N5581 2N5582	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	30	40	40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	60	75	75	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	6.0	6.0	Vdc
Collector Current — Continuous	I <sub>C</sub>	800	800	800	mA <sub>dc</sub>
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	0.8 4.57	0.4 2.28	0.6 3.33	Watt mW °C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	3.0 17.1	1.2 6.85	2.0 11.43	Watts mW °C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200			°C

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)**

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA <sub>dc</sub> , I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	30 40	—	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 μA <sub>dc</sub> , I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	60 75	—	Vdc
Emitter-Base Breakdown Voltage (I <sub>E</sub> = 10 μA <sub>dc</sub> , I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	5.0 6.0	—	Vdc
Collector Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> = 3.0 Vdc)	I <sub>CEX</sub>	—	10	nA <sub>dc</sub>
Collector Cutoff Current (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 60 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C) (V <sub>CB</sub> = 60 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C)	I <sub>CBO</sub>	— — — —	0.01 0.01 10 10	μA <sub>dc</sub>
Emitter Cutoff Current (V <sub>EB</sub> = 3.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	—	10	nA <sub>dc</sub>
Base Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> = 3.0 Vdc)	I <sub>BL</sub>	—	20	nA <sub>dc</sub>
<b>ON CHARACTERISTICS</b>				
DC Current Gain (I <sub>C</sub> = 0.1 mA <sub>dc</sub> , V <sub>CE</sub> = 10 Vdc)	h <sub>FE</sub>	20 35	—	—
(I <sub>C</sub> = 1.0 mA <sub>dc</sub> , V <sub>CE</sub> = 10 Vdc)		25 50	—	—
(I <sub>C</sub> = 10 mA <sub>dc</sub> , V <sub>CE</sub> = 10 Vdc)		35 75	—	—
(I <sub>C</sub> = 10 mA <sub>dc</sub> , V <sub>CE</sub> = 10 Vdc, T <sub>A</sub> = -55°C)		15 35	—	—
(I <sub>C</sub> = 150 mA <sub>dc</sub> , V <sub>CE</sub> = 10 Vdc)(1)		40 100	120 300	—

2N2218/19/21/22, A SERIES, 2N5581/82

ELECTRICAL CHARACTERISTICS (continued) (T<sub>A</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
(I <sub>C</sub> = 150 mAdc, V <sub>CE</sub> = 1.0 Vdc)(1)	2N2218,A, 2N2221,A, 2N5581 2N2219,A, 2N2222,A, 2N5582	20 50	— —	
(I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 10 Vdc)(1)	2N2218, 2N2221 2N2219, 2N2222 2N2218A, 2N2221A, 2N5581 2N2219A, 2N2222A, 2N5582	20 30 25 40	— — — —	
Collector-Emitter Saturation Voltage(1) (I <sub>C</sub> = 150 mAdc, I <sub>B</sub> = 15 mAdc)	Non-A Suffix A-Suffix, 2N5581, 2N5582	— —	0.4 0.3	Vdc
(I <sub>C</sub> = 500 mAdc, I <sub>B</sub> = 50 mAdc)	Non-A Suffix A-Suffix, 2N5581, 2N5582	— —	1.6 1.0	
Base-Emitter Saturation Voltage(1) (I <sub>C</sub> = 150 mAdc, I <sub>B</sub> = 15 mAdc)	Non-A Suffix A-Suffix, 2N5581, 2N5582	0.6 0.6	1.3 1.2	Vdc
(I <sub>C</sub> = 500 mAdc, I <sub>B</sub> = 50 mAdc)	Non-A Suffix A-Suffix, 2N5581, 2N5582	— —	2.6 2.0	

SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product(2) (I <sub>C</sub> = 20 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)	All Types, Except 2N2219A, 2N2222A, 2N5582	f <sub>T</sub>	250 300	— —	MHz
Output Capacitance(3) (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 100 kHz)		C <sub>obo</sub>	—	8.0	pF
Input Capacitance(3) (V <sub>EB</sub> = 0.5 Vdc, I <sub>C</sub> = 0, f = 100 kHz)	Non-A Suffix A-Suffix, 2N5581, 2N5582	C <sub>ibo</sub>	— —	30 25	pF
Input Impedance (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	2N2218A, 2N2221A 2N2219A, 2N2222A	h <sub>ie</sub>	1.0 2.0	3.5 8.0	kohms
(I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	2N2218A, 2N2221A 2N2219A, 2N2222A		0.2 0.25	1.0 1.25	
Voltage Feedback Ratio (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	2N2218A, 2N2221A 2N2219A, 2N2222A	h <sub>re</sub>	— —	5.0 8.0	X 10 <sup>-4</sup>
(I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	2N2218A, 2N2221A 2N2219A, 2N2222A		— —	2.5 4.0	
Small-Signal Current Gain (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	2N2218A, 2N2221A 2N2219A, 2N2222A	h <sub>fe</sub>	30 50	150 300	—
(I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	2N2218A, 2N2221A 2N2219A, 2N2222A		50 75	300 375	
Output Admittance (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	2N2218A, 2N2221A 2N2219A, 2N2222A	h <sub>oe</sub>	3.0 5.0	15 35	μmhos
(I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	2N2218A, 2N2221A 2N2219A, 2N2222A		10 25	100 200	
Collector Base Time Constant (I <sub>E</sub> = 20 mAdc, V <sub>CB</sub> = 20 Vdc, f = 31.8 MHz)	A-Suffix	rb'C <sub>C</sub>	—	150	ps
Noise Figure (I <sub>C</sub> = 100 μAdc, V <sub>CE</sub> = 10 Vdc, R <sub>S</sub> = 1.0 kohm, f = 1.0 kHz)	2N2219A, 2N2222A	NF	—	4.0	dB
Real Part of Common-Emitter High Frequency Input Impedance (I <sub>C</sub> = 20 mAdc, V <sub>CE</sub> = 20 Vdc, f = 300 MHz)	2N2218A, 2N2219A 2N2221A, 2N2222A	Re(h <sub>ie</sub> )	—	60	Ohms

(1) Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

(2) f<sub>T</sub> is defined as the frequency at which |h<sub>fe</sub>| extrapolates to unity.

(3) 2N5581 and 2N5582 are Listed C<sub>cb</sub> and C<sub>eb</sub> for these conditions and values.

SWITCHING TIME CHARACTERISTICS

FIGURE 9 — TURN-ON TIME

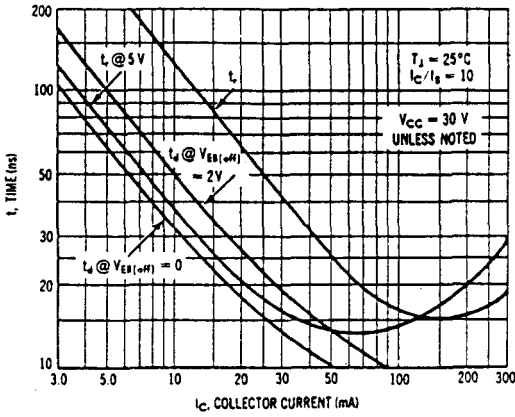


FIGURE 10 — CHARGE DATA

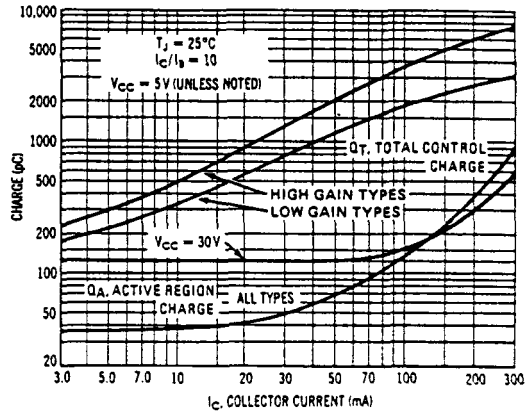


FIGURE 11 — TURN-OFF BEHAVIOR

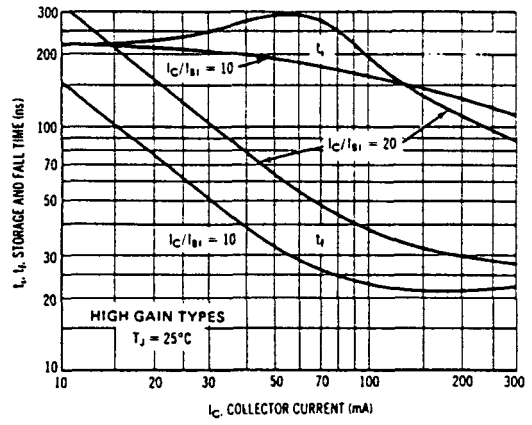
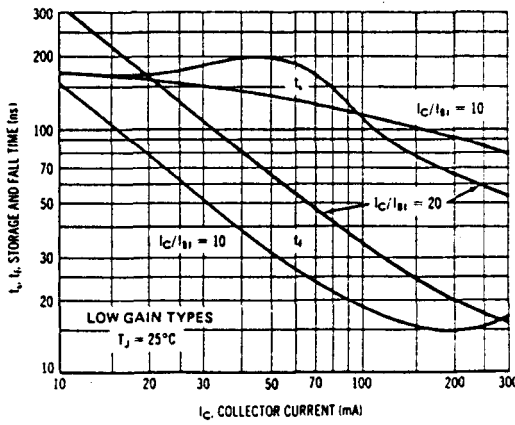




FIGURE 12 — DELAY AND RISE TIME EQUIVALENT TEST CIRCUIT

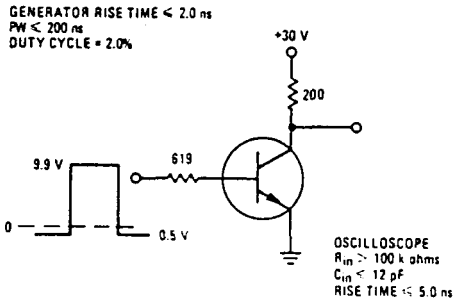
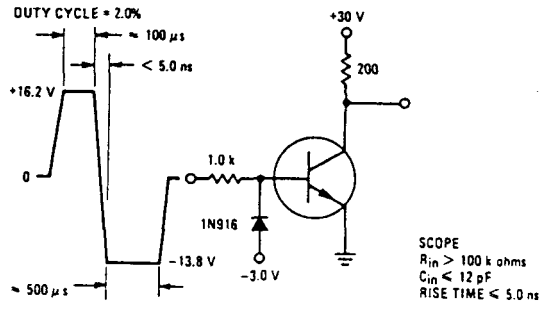


FIGURE 13 — STORAGE TIME AND FALL TIME EQUIVALENT TEST CIRCUIT



**MAXIMUM RATINGS**

Rating	Symbol	Non-A Suffix	A-Suffix	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	40	60	Vdc	
Collector-Base Voltage	V <sub>CBO</sub>	60		Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	5.0		Vdc	
Collector Current — Continuous	I <sub>C</sub>	600		mAdc	
		2N2904,A 2N2905,A	2N2906,A 2N2907,A	2N3485,A 2N3486,A	
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	600 3.43	400 2.28	400 2.28	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	3.0 17.2	1.8 10.3	2.0 11.43	Watts mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200		°C	

**2N2904,A, 2N2905,A,  
2N2906,A, 2N2907,A,  
2N3485,A, 2N3486,A**

JAN, JTX, JTXV AVAILABLE\*

CASE 79-02, STYLE 1  
2N2904/2905 TO-39 (TO-205AD)

CASE 22-03, STYLE 1  
2N2906/2907 TO-18 (TO-206AA)

CASE 26-03, STYLE 1  
2N3485/3486 TO-46 (TO-206AB)



**GENERAL PURPOSE TRANSISTOR**  
PNP SILICON

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted.)**

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector-Emitter Breakdown Voltage(1) (I <sub>C</sub> = 10 mAdc, I <sub>E</sub> = 0)	V <sub>(BR)CEO</sub>	40 60	—	—	Vdc
	Non-A Suffix A-Suffix				
Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	60	—	—	Vdc
Emitter-Base Breakdown Voltage (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	5.0	—	—	Vdc
Collector Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>BE</sub> = 0.5 Vdc)	I <sub>CEX</sub>	—	—	50	nAdc
Collector Cutoff Current (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	—	—	0.020 0.010	μAdc
	Non-A Suffix A-Suffix				
(V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C)	Non-A Suffix A-Suffix	—	—	20 10	
Base Current (V <sub>CE</sub> = 30 Vdc, V <sub>BE</sub> = 0.5 Vdc)	I <sub>B</sub>	—	—	50	nAdc
<b>ON CHARACTERISTICS</b>					
DC Current Gain (I <sub>C</sub> = 0.1 mAdc, V <sub>CE</sub> = 10 Vdc)	h <sub>FE</sub>	20 35 40 75	—	—	—
	2N2904, 2N2906, 2N3485 2N2905, 2N2907, 2N3486 2N2904A, 2N2906A, 2N3485A 2N2905A, 2N2907A, 2N3486A				
(I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc)	h <sub>FE</sub>	25 50 40 100	—	—	—
	2N2904, 2N2906, 2N3485 2N2905, 2N2907, 2N3486 2N2904A, 2N2906A, 2N3485A 2N2905A, 2N2907A, 2N3486A				
(I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc)	h <sub>FE</sub>	35 75 40 100	—	—	—
	2N2904, 2N2906, 2N3485 2N2905, 2N2907, 2N3486 2N2904A, 2N2906A, 2N3485A 2N2905A, 2N2907A, 2N3486A				
(I <sub>C</sub> = 150 mAdc, V <sub>CE</sub> = 10 Vdc)(1)	h <sub>FE</sub>	40 100	—	120 300	—
	2N2904A, 2N2906A, 2N3485A 2N2905A, 2N2907A, 2N3486A				

\*ALSO AVAILABLE 2N2905ALJANS AND 2N2907AJANS

SMALL-SIGNAL DEVICES

MOTOROLA SEMICONDUCTORS

2N2904,A, 2N2905,A, 2N2906,A, 2N2907,A, 2N3485,A, 2N3486,A

ELECTRICAL CHARACTERISTICS (continued) ( $T_A = 25^\circ\text{C}$  unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
( $I_C = 500\text{ mAdc}$ , $V_{CE} = 10\text{ Vdc}$ )(1)	2N2904, 2N2906, 2N3485 2N2905, 2N2907, 2N3486 2N2904A, 2N2906A, 2N3485A 2N2905A, 2N2907A, 2N3486A	20 30 40 50	— — — —	— — — —	
Collector-Emitter Saturation Voltage(1) ( $I_C = 150\text{ mAdc}$ , $I_B = 15\text{ mAdc}$ ) ( $I_C = 500\text{ mAdc}$ , $I_B = 50\text{ mAdc}$ )	$V_{CE(sat)}$	— —	— —	0.4 1.6	Vdc
Base-Emitter Saturation Voltage ( $I_C = 150\text{ mAdc}$ , $I_B = 15\text{ mAdc}$ )(1) ( $I_C = 500\text{ mAdc}$ , $I_B = 50\text{ mAdc}$ )	$V_{BE(sat)}$	— —	— —	1.3 2.6	Vdc

SMALL-SIGNAL CHARACTERISTICS

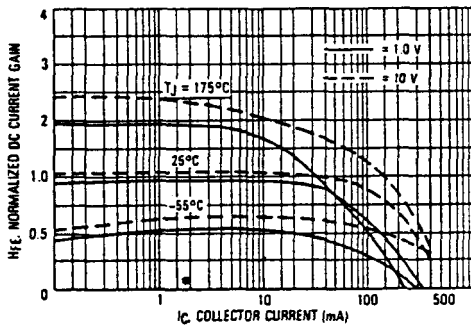
Current-Gain — Bandwidth Product(2) ( $I_C = 50\text{ mAdc}$ , $V_{CE} = 20\text{ Vdc}$ , $f = 100\text{ MHz}$ )	$f_T$	200	—	—	MHz
Output Capacitance ( $V_{CB} = 10\text{ Vdc}$ , $I_E = 0$ , $f = 100\text{ kHz}$ )	$C_{obo}$	—	—	8.0	pF
Input Capacitance ( $V_{BE} = 2.0\text{ Vdc}$ , $I_C = 0$ , $f = 100\text{ kHz}$ )	$C_{ibo}$	—	—	30	pF

SWITCHING CHARACTERISTICS

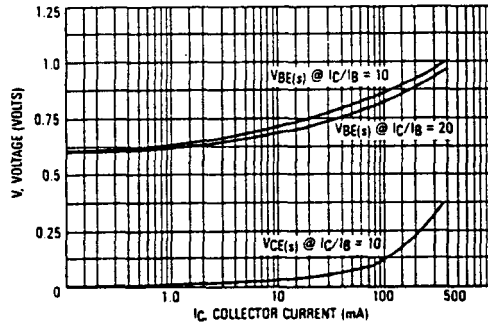
Turn-On Time	$(V_{CC} = 30\text{ Vdc}$ , $I_C = 150\text{ mAdc}$ , $I_{B1} = 15\text{ mAdc}$ )	$t_{on}$	—	26	45	ns
Delay Time		$t_d$	—	6.0	10	ns
Rise Time		$t_r$	—	20	40	ns
Turn-Off Time	$(V_{CC} = 6.0\text{ Vdc}$ , $I_C = 150\text{ mAdc}$ , $I_{B1} = I_{B2} = 15\text{ mAdc}$ )	$t_{off}$	—	70	100	ns
Storage Time		$t_s$	—	50	80	ns
Fall Time		$t_f$	—	20	30	ns

- (1) Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$   
 (2)  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

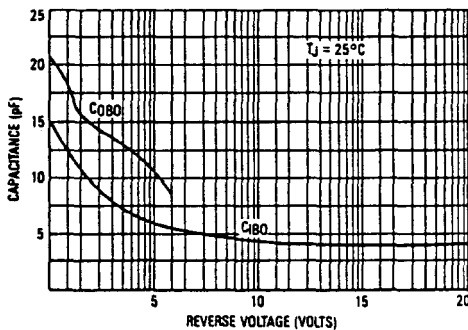
NORMALIZED DC CURRENT GAIN



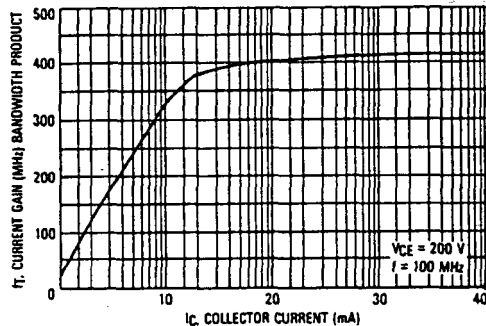
"ON" VOLTAGE



CAPACITANCE

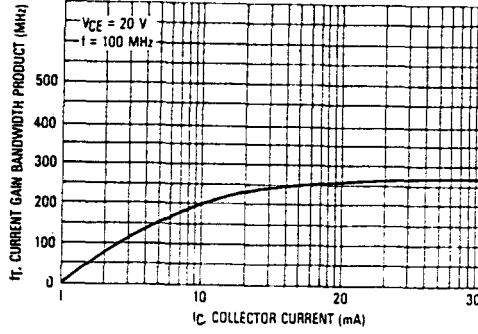


CURRENT GAIN—BANDWIDTH PRODUCT

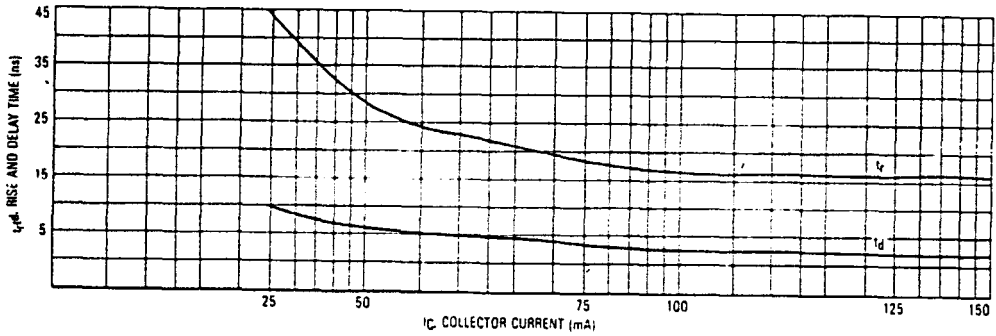


2N2904,A, 2N2905,A, 2N2906,A, 2N2907,A, 2N3485,A, 2N3486,A

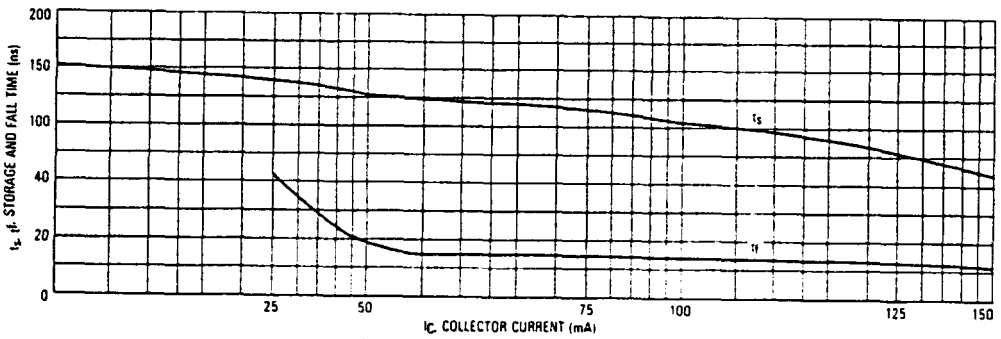
CURRENT GAIN — BANDWIDTH PRODUCT



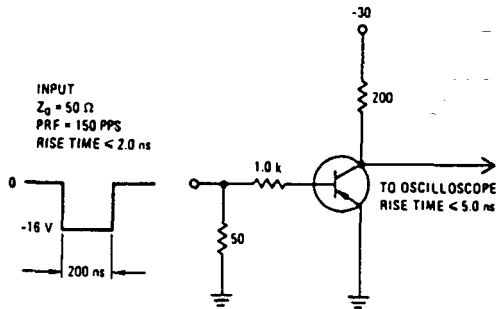
TURN ON BEHAVIOR



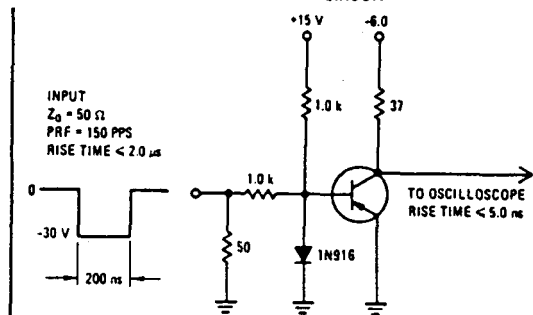
TURN OFF BEHAVIOR



DELAY AND RISE TIME TEST CIRCUIT



STORAGE AND FALL TIME TEST CIRCUIT



TRANSISTOR NUMBER	P M O A L T	PACI-AGE	LEAD INFO	Ve MAX	Vc MAX	Ve MAX	Ic MAX	Tc MAX	PTOT	Fc MIN	Co MAX	He	He BIAS	USE	MFR	ALTERNATIVES AND NOTES
2N6705	N S	X54D	M01	15V	25V	2V	1500mA	175C	19VC	-	12P	20mm	100mA	RMA	TRW	-
2N6706	N S	X54D	M01	55V	25V	2V	200mA	175C	5WC	-	12P	20mm	50mA	RMA	TRW	-
2N6707	N S	X54D	M01	55V	25V	2V	200mA	175C	19VC	-	10P	20mm	100mA	RMA	TRW	-
2N6708	N S	X54D	M01	55V	25V	2V	700mA	175C	20VC	-	10P	20mm	100mA	RMA	TRW	-
2N6709	N S	T092	L14	40V	15V	4V	600mA	150C	425mWF	500M	4P8	40/20	10mA	VMS	J&T	B5511 2N2389A
2N6710	N S	T092	L14	30V	15V	4V	50mA	150C	425mWF	800M	1P7	20mm	3mA	ULA	NAT	2N5173
2N6711	P S	T092	L14	15V	15V	4V	50mA	15V	310mWF	700M	3P8	50/120	10mA	ULA	NAT	2N4958
2N6712	N S	T092	L14	40V	15V	5V	500mA	150C	825mWF	350M	5P8	30/120	30mA	VMS	NAT	B5511 2N2389A
2N6713	N S	X27	L84	85V	25V	3V	500mA	200C	5WC	-	4P5	20/200	100mA	UMP	TRW	-
2N6714	N S	X44	X44	85V	25V	3V	1500mA	200C	18VC	-	14P	20/200	100mA	UMP	TRW	-
2N6715	N S	X208	-	85V	25V	3V	3A	175C	49VC	-	26P	10/150	100mA	RMG	TRW	-
2N6716	N S	X208	-	85V	25V	3V	3A	175C	79VC	-	50P	10/150	200mA	RMG	TRW	-
2N6717	P S	T038	L04	80V	60V	5V	3500mA	200C	10VC	8M	-	20/100	1A	RHG	RCA	2N6193
2N6718	P S	T038	L04	60V	50V	5V	3800mA	200C	10VC	8M	-	20/100	1A	RHG	RCA	2N6193
2N6719	P S	T038	L04	15V	40V	5V	3800mA	200C	10VC	8M	-	20/100	100mA	RHG	RCA	2N6193
2N6720	N S	T038	L04	60V	60V	5V	3600mA	200C	10VC	1M	-	20/100	1A	RHG	RCA	BSV64
2N6721	N S	T038	L04	60V	50V	5V	3800mA	200C	10VC	1M	-	20/100	1200mA	RHG	RCA	BSV64
2N6722	N S	T038	L04	45V	40V	5V	3600mA	200C	10VC	1M	-	20/100	1800mA	RHG	RCA	BSV64
2N6723	N S	T077	N01	75V	40V	6V	800mA	200C	600mWF	250M	8P0	40/120	150mA	DUA	MOT	8FX10
2N6724	N S	T077	N01	75V	40V	6V	800mA	200C	600mWF	250M	8P0	100mm	180mA	DUA	MOT	8FX10
2N6725	P S	T077	N01	80V	80V	5V	800mA	200C	600mWF	200M	8P8	40/120	180mA	DUA	MOT	8FX11
2N6726	P S	T077	N01	80V	80V	5V	800mA	200C	600mWF	200M	8P8	100mm	180mA	DUA	MOT	8FX11
2N6727	N S	T03	L08	300V	225V	6V	5A	200C	110VC	18M	-	10/100	2A	RHE	RCA	BUX18C
2N6728	N S	T03	L08	375V	260V	6V	5A	200C	110VC	18M	-	10/100	2A	RHE	RCA	BUX18C
2N6729	N S	X10	L20	25V	25V	5V	750mA	125C	500mWF	100M	15P	45mm	500mA	AMG	GES	BC338
2N6730	P S	X16	L30	25V	25V	5V	750mA	125C	500mWF	100M	15P	45mm	500mA	AMG	GES	BC328
2N6731	N S	X16	L30	25V	25V	5V	750mA	125C	500mWF	138M	15P	60mm	900mA	AMG	GES	BC338
2N6732	P S	X16	L30	25V	25V	5V	750mA	125C	500mWF	138M	15P	60mm	900mA	AMG	GES	BC328
2N6733	N S	X16	L30	50V	40V	5V	750mA	125C	500mWF	100M	15P	60/120	2mA	AMG	GES	BC337
2N6734	P S	X16	L30	50V	40V	5V	750mA	125C	500mWF	100M	15P	60/120	2mA	AMG	GES	BC327
2N6735	N S	X10	L20	50V	40V	5V	750mA	125C	500mWF	120M	15P	100mm	2mA	AMG	GES	BC337
2N6736	N S	X16	L30	50V	40V	5V	750mA	125C	500mWF	120M	15P	100mm	2mA	AMG	GES	BC327
2N6737	N S	X16	L30	50V	40V	5V	750mA	125C	500mWF	138M	15P	150mm	2mA	AMG	GES	BC337
2N6738	P S	X16	L30	70V	60V	5V	750mA	125C	500mWF	100M	15P	20mm	900mA	AMH	GES	BC337
2N6739	P S	X16	L30	70V	60V	5V	750mA	125C	500mWF	120M	15P	25mm	500mA	AMH	GES	BC337
2N6740	N S	X16	L30	70V	60V	5V	750mA	125C	500mWF	120M	15P	25mm	500mA	AMH	GES	BC327
2N6741	N S	X16	L30	50V	40V	5V	100mA	125C	380mWF	90M	4P8	80/120	3mA	ALG	GES	BC327
2N6742	N S	X16	L30	50V	40V	5V	100mA	125C	380mWF	90M	4P8	100mm	3mA	ALG	GES	BC327
2N6743	N S	X16	L30	50V	40V	5V	100mA	125C	380mWF	90M	4P8	150mm	2mA	ALG	GES	BC327
2N6744	N S	X16	L30	50V	40V	5V	100mA	125C	380mWF	90M	4P8	200mm	2mA	ALN	GES	BC327
2N6745	N S	X16	L30	50V	40V	5V	100mA	125C	380mWF	90M	4P8	250mm	2mA	ALN	GES	BC327
2N6746	N S	X16	L30	50V	40V	5V	100mA	125C	380mWF	90M	4P8	400mm	2mA	ALN	GES	BC327
2N6747	N S	X16	L30	50V	40V	5V	100mA	125C	380mWF	90M	4P8	400mm	2mA	ALN	GES	BC327
2N6748	P S	T072	L06	30V	30V	2V	30mA	200C	200mWF	1200M	0P8	20/150	2mA	ULA	MOT	2N4261
2N6749	N S	T092	L14	120V	100V	5V	800mA	150C	625mWF	100M	4P8	80/500	10mA	TVN	PCD	BCX22
2N6750	N S	T092	L14	180V	140V	5V	800mA	150C	625mWF	100M	4P8	80/250	18mA	TVN	PCD	8FT37
2N6751	N S	T092	L14	180V	140V	5V	800mA	150C	625mWF	100M	4P8	175mm	10mA	TVN	NAT	2N5861
2N6752	N S	T092	L14	200V	180V	6V	800mA	150C	625mWF	100M	4P8	50/250	10mA	TVN	PCD	2N6917
2N6753	P S	T08	L04	80V	40V	4V	1A	175C	5WC	-	10mm	10mm	250mA	VMS	TS	BC161
2N6754	N S	T072	L06	15V	15V	2V	16mA	200C	200mWF	2500M	0P8	25mm	10mA	SLG	MOT	-
2N6755	N S	T048	L01	10V	10V	2V	200mA	200C	2WC	20	3P8	25mm	50mA	SMG	MOT	-
2N6756	N S	T048	L01	10V	5V	2V	300mA	200C	2WC	1700M	5P8	25mm	100mA	SMG	MOT	8FT17
2N6757	N S	T03	L06	375V	275V	6V	3A	200C	100VC	5M	-	8/48	3A	RHE	RCA	BUX18C
2N6758	N S	T03	L06	300V	275V	6V	3A	200C	100VC	5M	-	10/50	2A	RHE	RCA	BUX18C
2N6759	N S	T072	L06	30V	10V	2V	100mA	200C	380mWF	2200M	1P5	25/200	25mA	SMS	MOT	-
2N6760	N S	T072	L06	30V	10V	2V	100mA	200C	380mWF	1700M	1P5	25/250	25mA	SMS	MOT	-
2N6761	P S	T077	N01	50V	40V	3V	50mA	200C	600mWF	200M	6P8	50/150	1mA	DUA	MOT	8% DVBE
2N6762	P S	T077	N01	50V	40V	3V	50mA	200C	600mWF	250M	8P8	100mm	1mA	DUA	MOT	8% DVBE
2N6763	N S	T092	L14	50V	40V	6V	1A	150C	625mWF	200M	9P8	25/150	500mA	VMS	MOT	2N6558
2N6764	N S	X28	L46	30V	18V	4V	1A	200C	10VC	-	25P	5mm	250mA	VMP	MOT	-
2N6765	N S	X28	L46	30V	18V	4V	2A	200C	20VC	-	50P	5mm	500mA	VMP	MOT	-
2N6766	N S	X28	L46	40V	24V	4V	2600mA	200C	50VC	-	125P	3mm	1200mA	RHP	MOT	-
2N6767	N S	X28	L46	40V	24V	4V	7A	200C	100VC	-	238P	3mm	2500mA	RHP	MOT	-
2N6768	N S	T072	L06	30V	15V	4V	100mA	200C	500mWF	800M	1P5	40mm	10mA	SMG	MOT	2N5852
2N6769	N S	T072	L06	30V	15V	4V	100mA	200C	500mWF	1100M	1P5	40mm	10mA	SMG	MOT	2N5852
2N6770	P S	T081	L46	100V	80V	8V	10A	200C	88VC	18M	-	30/90	5A	RHH	KER	BOV60
2N6771	N S	T041	L46	100V	80V	8V	10A	200C	88VC	20M	-	30/90	5A	RHH	KER	BOV63
2N6772	P S	T0105	L04	80V	80V	5V	1A	125C	750mWF	15M	100P	50/300	150mA	AMG	PCD	8F595
2N6773	N S	T0105	L04	80V	80V	5V	1A	125C	750mWF	200M	12P	50/300	50mA	AMG	PCD	8F596
2N6774	P S	T0105	L04	80V	80V	5V	1A	125C	750mWF	15M	100P	50/300	150mA	AMG	PCD	8F593
2N6775	N S	T0105	L04	80V	80V	5V	1A	125C	750mWF	200M	12P	50/300	50mA	AMG	PCD	8F594



BIODATA

## **BIODATA**

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